

L Number	Hits	Search Text	DB	Tim stamp
1	627	display and semiconductor and (i n adj implant\$) and lectr de and drain and gat and method and capacit r	US-PGPUB; EPO; JPO; DERWENT; IBM_TDB USOCR	2004/05/17 06:02
2	0	display and semiconductor and (ion adj implant\$) and electrode and drain and gate and method and capacitor		2004/05/17 06:02
3	3	display and semiconductor and (ion adj implant\$) and electrode and drain and gate and method and capacitor	EPO; JPO; DERWENT; IBM_TDB	2004/05/17 06:02
4	624	display and semiconductor and (ion adj implant\$) and electrode and drain and gate and method and capacitor	US-PGPUB	2004/05/17 06:02